

International
IR Rectifier

MUR1520
MURB1520
MURB1520-1

Ultrafast Rectifier

Features

- Ultrafast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 175°C Operating Junction Temperature

$$t_{rr} = 35\text{ns}$$

$$I_{F(AV)} = 15\text{Amp}$$

$$V_R = 200\text{V}$$

Description/ Applications

International Rectifier's MUR... series are the state of the art Ultra fast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultra fast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

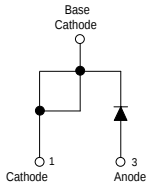
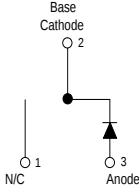
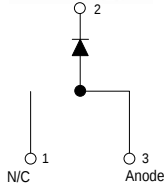
These devices are intended for use in the output rectification stage of SMPS, UPS, DC-DC converters as well as free-wheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Absolute Maximum Ratings

Parameters	Max	Units
V_{RRM} Peak Repetitive Peak Reverse Voltage	200	V
$I_{F(AV)}$ Average Rectified Forward Current Total Device, (Rated V_R), $T_C = 150^\circ\text{C}$	15	A
I_{FSM} Non Repetitive Peak Surge Current	200	
I_{FM} Peak Repetitive Forward Current (Rated V_R , Square wave, 20 KHz), $T_C = 150^\circ\text{C}$	30	
T_J, T_{STG} Operating Junction and Storage Temperatures	-65 to 175	$^\circ\text{C}$

Case Styles

MUR1520	MURB1520	MUR1520-1
  TO-220AC	  D²PAK	  TO-262

Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
V _{BR} , V _r Breakdown Voltage, Blocking Voltage	200	-	-	V	I _R = 100μA
V _F Forward Voltage	-	-	1.05	V	I _F = 15A
	-	-	0.85	V	I _F = 15A, T _J = 150°C
I _R Reverse Leakage Current	-	-	10	μA	V _R = V _R Rated
	-	-	500	μA	T _J = 150°C, V _R = V _R Rated
C _T Junction Capacitance	-	55	-	pF	V _R = 200V
L _S Series Inductance	-	8.0	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
t _{rr} Reverse Recovery Time	-	-	35	ns	I _F = 1.0A, di _F /dt = 50A/μs, V _R = 30V
	-	22	-		T _J = 25°C
	-	39	-		T _J = 125°C
I _{RRM} Peak Recovery Current	-	1.6	-	A	T _J = 25°C
	-	4.1	-		T _J = 125°C
Q _{rr} Reverse Recovery Charge	-	19	-	nC	T _J = 25°C
	-	90	-		T _J = 125°C

Thermal - Mechanical Characteristics

Parameters	Min	Typ	Max	Units
T _J Max. Junction Temperature Range	- 65	-	175	°C
T _{Stg} Max. Storage Temperature Range	- 65	-	175	
R _{thJC} Thermal Resistance, Junction to Case	-	-	1.5	°C/ W
R _{thJA} Thermal Resistance, Junction to Ambient	-	-	50	
R _{thCS} ^① Thermal Resistance, Case to Heatsink	-	0.5	-	
Wt Weight	-	2.0	-	g
	-	0.07	-	(oz)
Mounting Torque	6.0	-	12	Kg-cm
	5.0	-	10	lbf.in

① Mounting Surface, Flat, Smooth and Greased

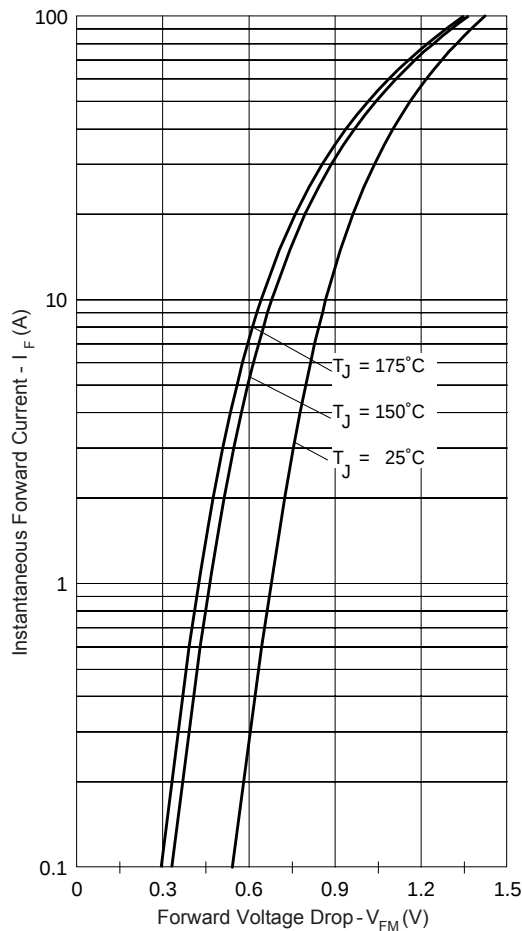


Fig. 1 - Typical Forward Voltage Drop Characteristics

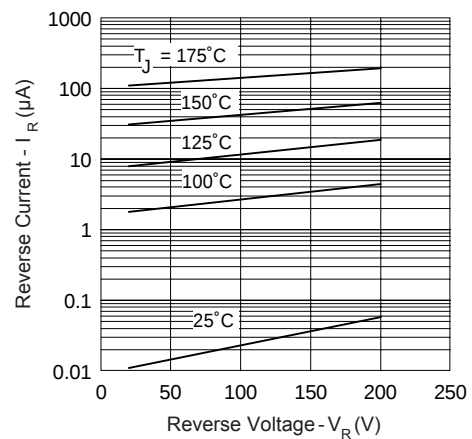


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

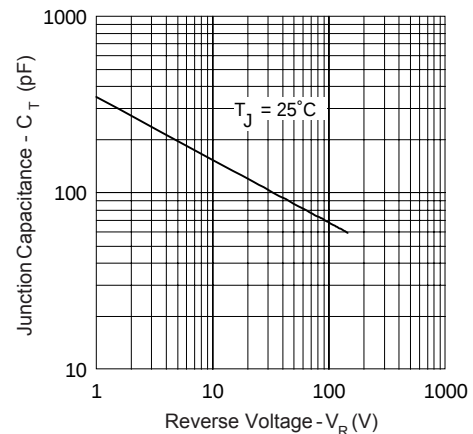


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

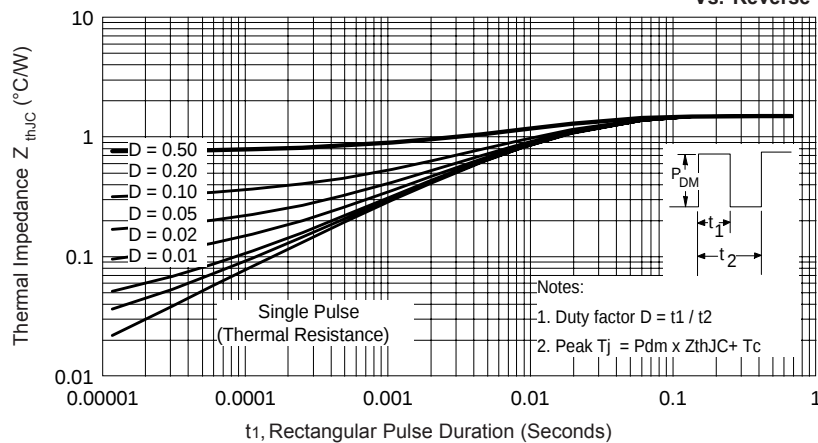


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

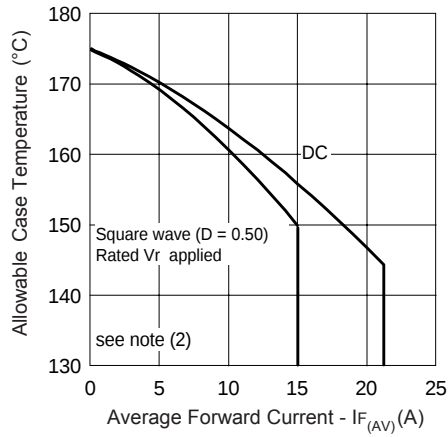


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

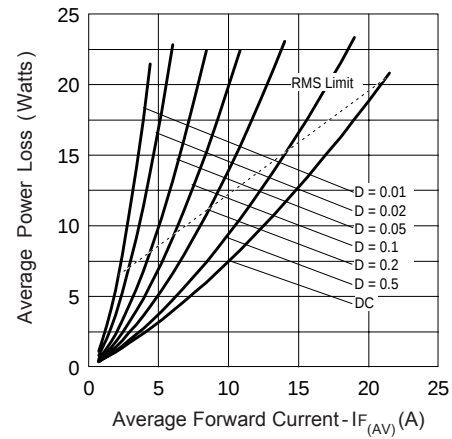


Fig. 6 - Forward Power Loss Characteristics

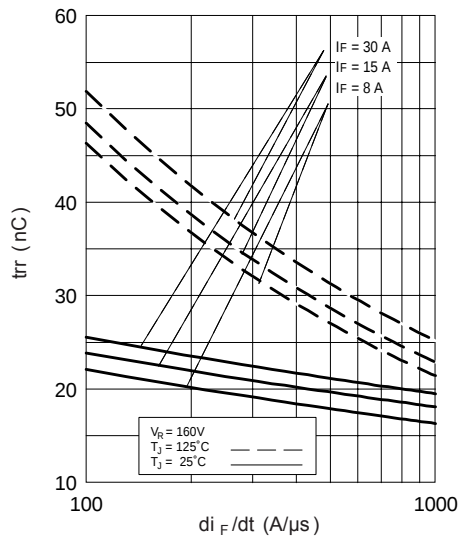


Fig. 7 - Typical Reverse Recovery vs. di_F/dt

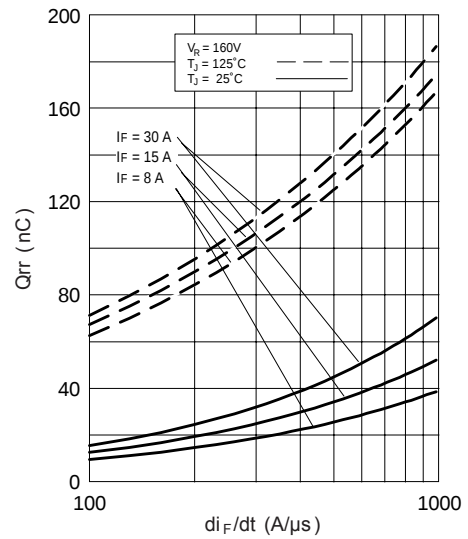


Fig. 8 - Typical Stored Charge vs. di_F/dt

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1}$ = rated V_R

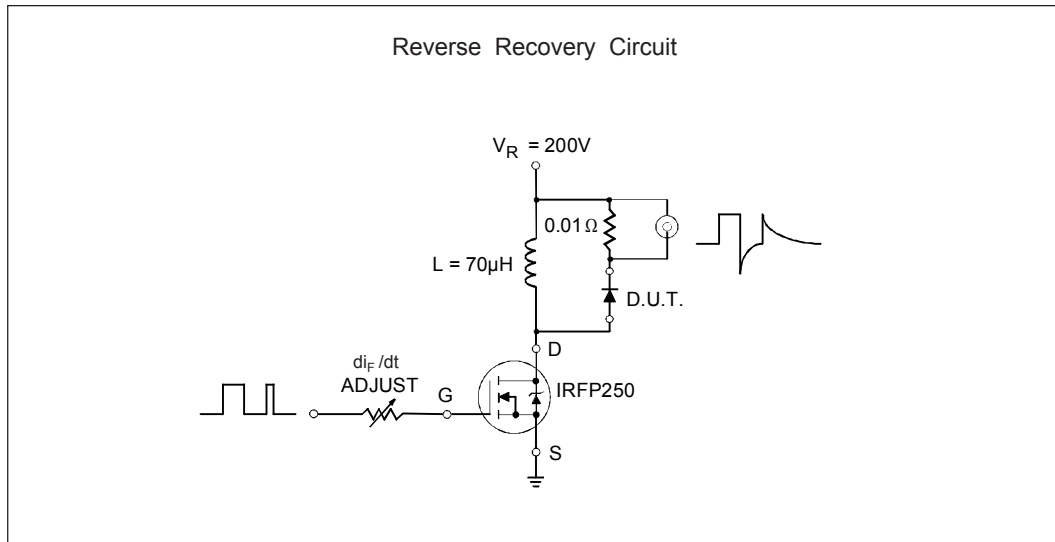


Fig. 9- Reverse Recovery Parameter Test Circuit

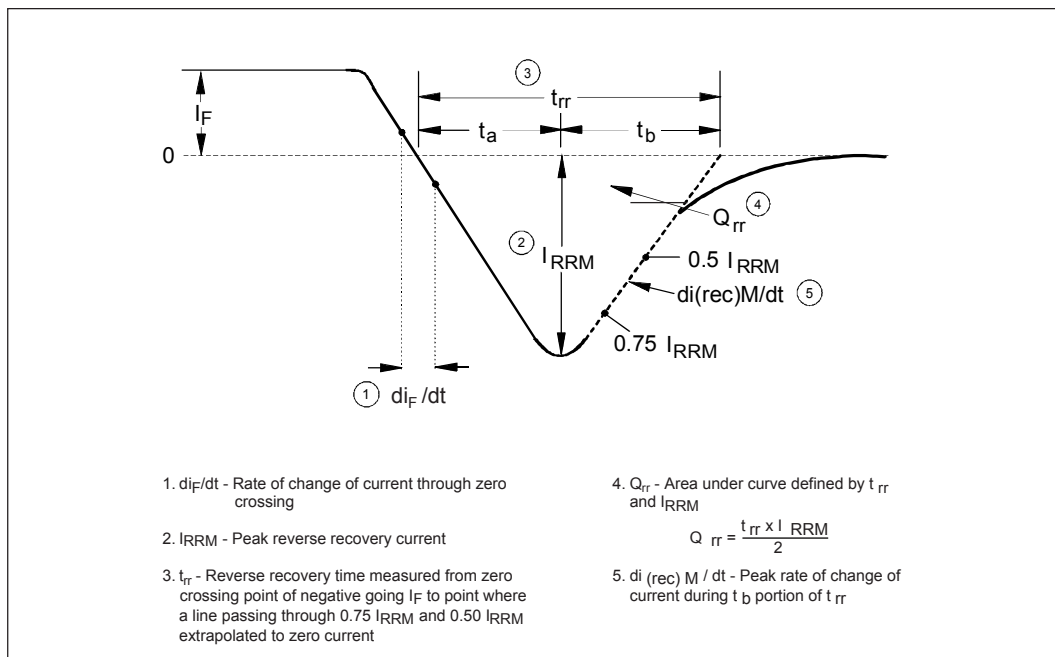
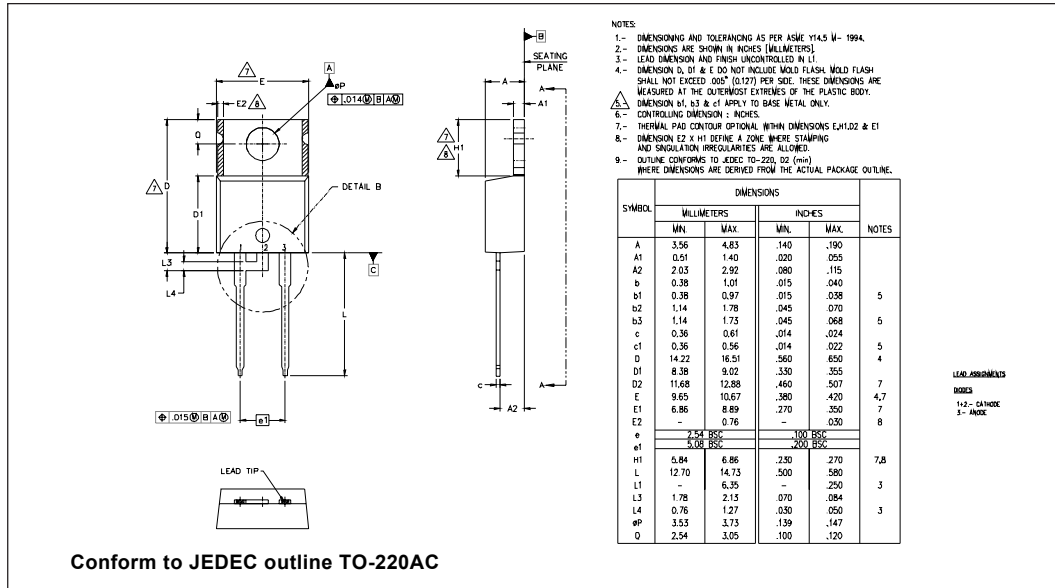
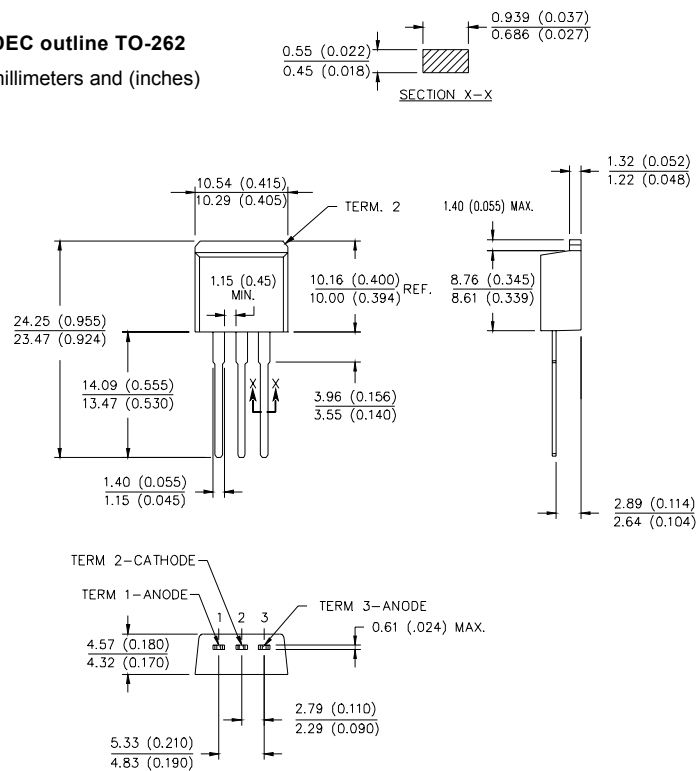


Fig. 10 - Reverse Recovery Waveform and Definitions

Outline Table



Modified JEDEC outline TO-262
 Dimensions in millimeters and (inches)



Outline Table

Conform to JEDEC outline D²Pak (SMD-220)

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES]
3. DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.127 [0.005"] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
4. DIMENSION b1 AND c1 APPLY TO BASE METAL ONLY.
5. CONTROLLING DIMENSION: INCH.

SYMBOL	DIMENSIONS		NOTES
	MILLIMETERS	INCHES	
A	4.06	4.83	.160 .190
A1	0.00	0.254	.000 .010
b	0.51	0.99	.020 .039
b1	0.51	0.89	.020 .035
b2	1.14	1.78	.045 .070
c	0.38	0.74	.015 .029
c1	0.38	0.58	.015 .023
c2	1.14	1.65	.045 .065
D	8.51	9.65	.335 .380
D1	6.86		.270
E	9.65	10.67	.380 .420
E1	6.22		.245
e	2.54 BSC		.100 BSC
H	14.61	15.88	.575 .625
L	1.78	2.79	.070 .110
L1	1.27	1.65	.050 .065
L2	1.27	1.78	.050 .070
L3	0.25 BSC		.010 BSC
L4	4.78	5.28	.188 .208
m	17.78		.700
m1	8.89		.350
n	11.43		.450
o	2.08		.082
p	3.81		.150
R	0.51	0.71	.020 .028
ø	90°	93°	90° 93°

LEAD ASSIGNMENTS

HEXFET

1.- GATE
2, 4.- DRAIN
3.- SOURCE

IGBTs, CoPACK

1.- GATE
2, 4.- COLLECTOR
3.- EMITTER

DIODES

1.- ANODE +
2, 4.- CATHODE
3.- ANODE

* PART DEPENDENT.

Ordering Information Table

Device Code						
MUR	B	15	20	CT	-1	-
①	②	③	④	⑤	⑥	⑦
1	- Ultrafast MUR Series					
2	- B = D ² Pak/ TO-262 None = TO-220AC					
3	- Current Rating (15 = 15A)					
4	- Voltage Rating (20 = 200V)					
5	- CT = Center Tap (Dual) TO-220 /D ² PAK/ TO-262					
6	- "-1" = TO-262 Option					
7	- • none = Standard Production • PbF = Lead-Free					

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MUR1520
*****
* SPICE Model Diode *
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.SUBCKT MUR1520 ANO CAT
D1 ANO 1 CAT
*Define diode model
.MODEL DMOD D Is=16.9E-09 N=1.332 Rs=4.439E-03 Ikf=.232 Xti=2 Eg=1.11
Cjo=700.3E-09 M=.3715 Vj=.1784 Fc=.5 Isr=1.389E-09
Nr=3.002 Bv=270 Ibv=95.79E-6 Tt=10.49E-9)

*****

.ENDS MUR1520

Thermal Model Subcircuit
.SUBCKT MUR1520 5 1

CTHERM1 5 4 2.23E+01
CTHERM2 4 3 1.23E+02
CTHERM3 3 2 3.35E+02
CTHERM4 2 1 4.75E+02

RTHERM1 5 4 7.55E-01
RTHERM2 4 3 5.90E-02
RTHERM1 3 2 1.01E-01
RTHERM1 2 1 5.43E-02

.ENDS MUR1520

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Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

International
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